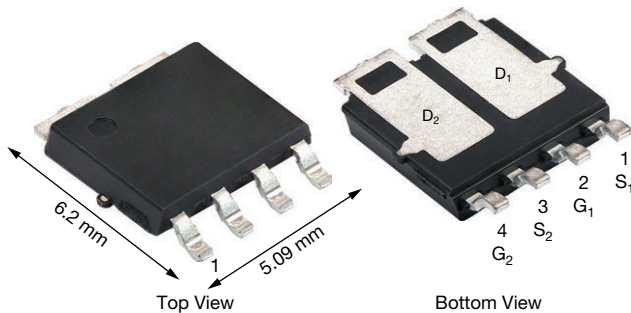
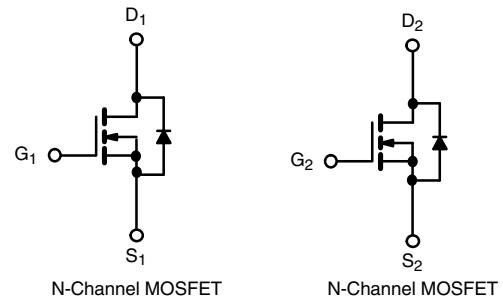


# Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

**PowerPAK® SO-8L Dual BWL**

**FEATURES**

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>g</sub> and UIS tested
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

 AUTOMOTIVE  
GRADE

**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**


PRODUCT SUMMARY	
V <sub>DS</sub> (V)	60
R <sub>DS(on)</sub> (Ω) at V <sub>GS</sub> = 10 V	0.0105
R <sub>DS(on)</sub> (Ω) at V <sub>GS</sub> = 4.5 V	0.0146
I <sub>D</sub> (A) per leg <sup>e</sup>	62
Configuration	Dual

ORDERING INFORMATION	
Package	PowerPAK® SO-8L
Lead (Pb)-free and halogen-free	SQJ764ELP (for detailed order number please see <a href="http://www.vishay.com/doc?79771">www.vishay.com/doc?79771</a> )

ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub> = 25 °C, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>GS</sub>	± 20	
Continuous Drain Current <sup>e</sup>	I <sub>D</sub>	T <sub>C</sub> = 25 °C <sup>a</sup>	62
		T <sub>C</sub> = 125 °C	36
Continuous Source Current (Diode conduction) <sup>e</sup>	I <sub>S</sub>	62	A
Pulsed Drain Current <sup>b, e</sup>	I <sub>DM</sub>	102	
Single Pulse Avalanche Current	I <sub>AS</sub>	24.5	mJ
Single Pulse Avalanche Energy	E <sub>AS</sub>	30	
Maximum Power Dissipation <sup>b, e</sup>	P <sub>D</sub>	T <sub>C</sub> = 25 °C	86
		T <sub>C</sub> = 125 °C	28
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C
Soldering Recommendations (Peak temperature)		260	

THERMAL RESISTANCE RATINGS				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	R <sub>thJA</sub>	52	°C/W	
Junction-to-Case (Drain) <sup>d</sup>	R <sub>thJC</sub>	1.74		

**Notes**

- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR4 material)
- See solder profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)).
- As per on JESD51-14
- Values based on R<sub>thJC</sub> and T<sub>C</sub> of 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system.



SPECIFICATIONS ( $T_C = 25\text{ }^\circ\text{C}$ , unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
<b>Static</b>							
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0\text{ V}$ , $I_D = 250\text{ }\mu\text{A}$		60	-	-	V
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\text{ }\mu\text{A}$		1.2	2.0	2.5	
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}$ , $V_{GS} = \pm 20\text{ V}$		-	-	$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{GS} = 0\text{ V}$	$V_{DS} = 60\text{ V}$	-	-	1	$\mu\text{A}$
		$V_{GS} = 0\text{ V}$	$V_{DS} = 60\text{ V}$ , $T_J = 125\text{ }^\circ\text{C}$	-	-	50	
		$V_{GS} = 0\text{ V}$	$V_{DS} = 60\text{ V}$ , $T_J = 175\text{ }^\circ\text{C}$	-	-	150	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{GS} = 10\text{ V}$	$V_{DS} \geq 5\text{ V}$	10	-	-	A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 10\text{ V}$	$I_D = 7\text{ A}$	-	0.0088	0.0105	$\Omega$
		$V_{GS} = 4.5\text{ V}$	$I_D = 7\text{ A}$	-	0.0117	0.0146	
		$V_{GS} = 10\text{ V}$	$I_D = 7\text{ A}$ , $T_J = 125\text{ }^\circ\text{C}$	-	-	0.0178	
		$V_{GS} = 10\text{ V}$	$I_D = 7\text{ A}$ , $T_J = 175\text{ }^\circ\text{C}$	-	-	0.0220	
Forward Transconductance <sup>b</sup>	$g_{fs}$	$V_{DS} = 15\text{ V}$ , $I_D = 20\text{ A}$		-	50	-	S
<b>Dynamic <sup>b</sup></b>							
Input Capacitance	$C_{iss}$	$V_{GS} = 0\text{ V}$	$V_{DS} = 25\text{ V}$ , $f = 1\text{ MHz}$	-	1275	1785	$\text{pF}$
Output Capacitance	$C_{oss}$			-	486	681	
Reverse Transfer Capacitance	$C_{rss}$			-	15	21	
Total Gate Charge <sup>c</sup>	$Q_g$	$V_{GS} = 10\text{ V}$	$V_{DS} = 30\text{ V}$ , $I_D = 15\text{ A}$	-	17	26	$\text{nC}$
Gate-Source Charge <sup>c</sup>	$Q_{gs}$			-	5	-	
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$			-	2	-	
Gate Resistance	$R_g$	$f = 1\text{ MHz}$		1	2	3	$\Omega$
Turn-On Delay Time <sup>c</sup>	$t_{d(on)}$	$V_{DD} = 30\text{ V}$ , $R_L = 2\text{ }\Omega$ $I_D \cong 15\text{ A}$ , $V_{GEN} = 10\text{ V}$ , $R_g = 1\text{ }\Omega$		-	10	15	$\text{ns}$
Rise Time <sup>c</sup>	$t_r$			-	3	6	
Turn-Off Delay Time <sup>c</sup>	$t_{d(off)}$			-	20	30	
Fall Time <sup>c</sup>	$t_f$			-	2	4	
<b>Source-Drain Diode Ratings and Characteristics <sup>b</sup></b>							
Pulsed Current <sup>a</sup>	$I_{SM}$			-	-	102	A
Forward Voltage	$V_{SD}$	$I_F = 7\text{ A}$ , $V_{GS} = 0\text{ V}$		-	0.88	1.2	V
Body diode reverse recovery time	$t_{rr}$	$I_F = 10\text{ A}$ , $di/dt = 100\text{A}/\mu\text{s}$		-	30	60	ns
Body diode reverse recovery charge	$Q_{rr}$			-	16	32	nC
Reverse recovery fall time	$t_a$			-	11	-	ns
Reverse recovery rise time	$t_b$			-	19	-	
Body diode peak reverse recovery current	$I_{RM(REC)}$					-	-1.1

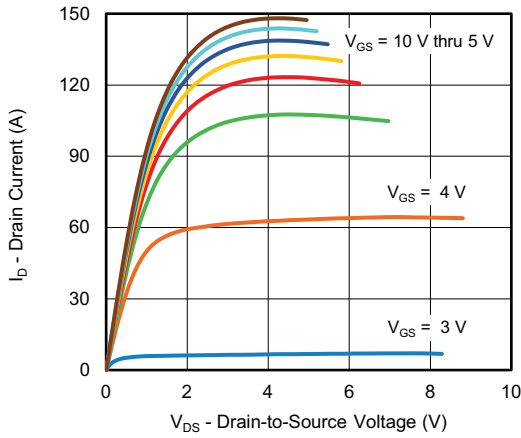
**Notes**

- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$   
b. Guaranteed by design, not subject to production testing  
c. Independent of operating temperature

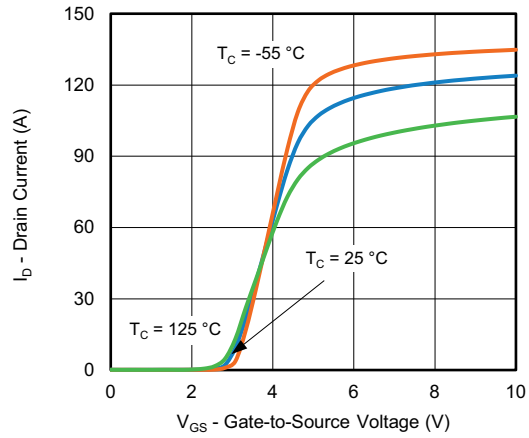
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



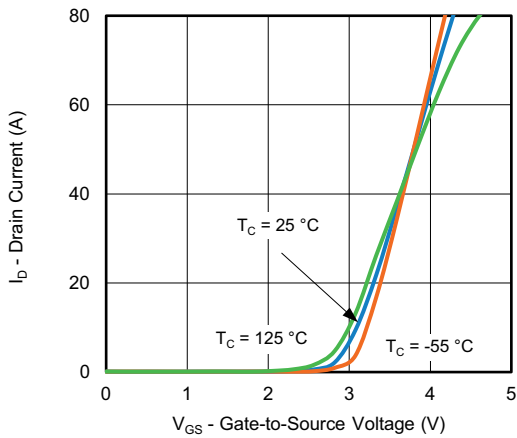
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



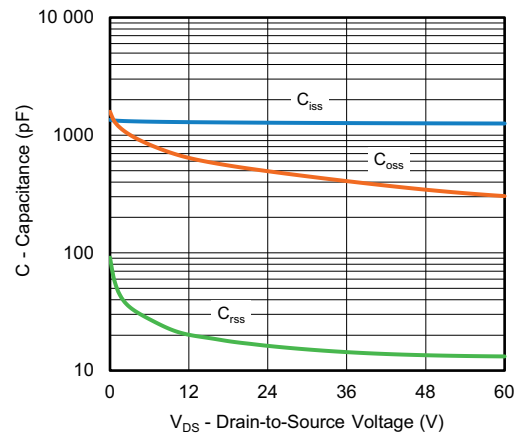
Output Characteristics



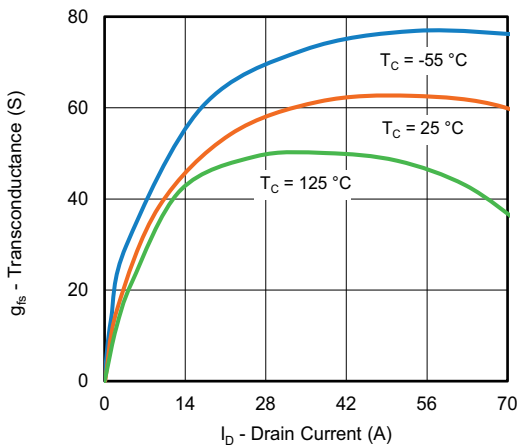
Transfer Characteristics



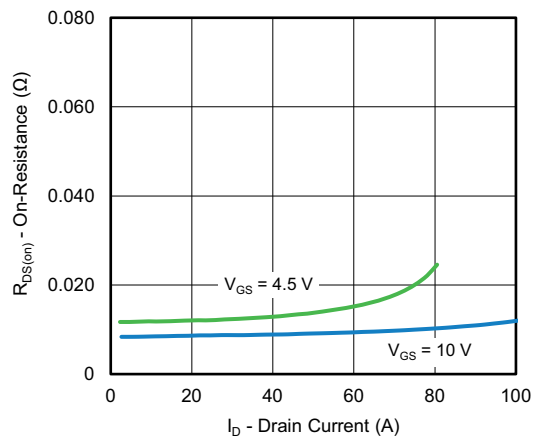
Transfer Characteristics



Capacitance



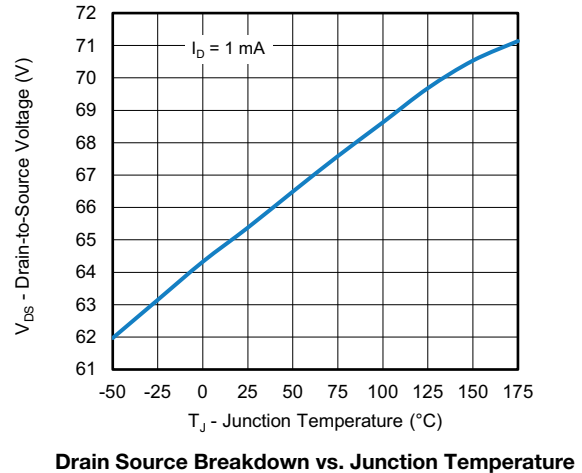
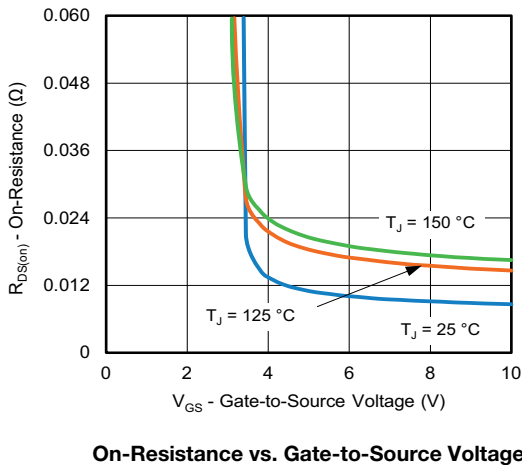
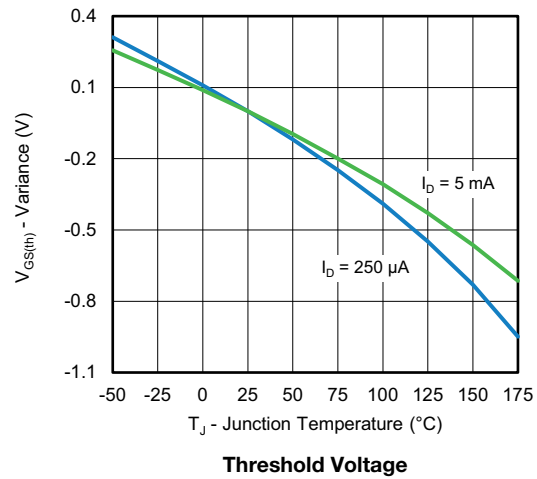
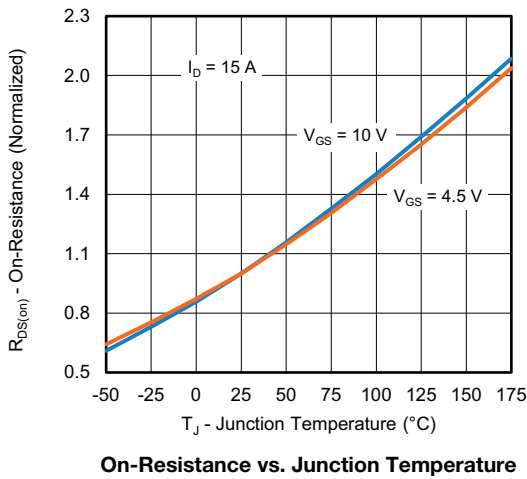
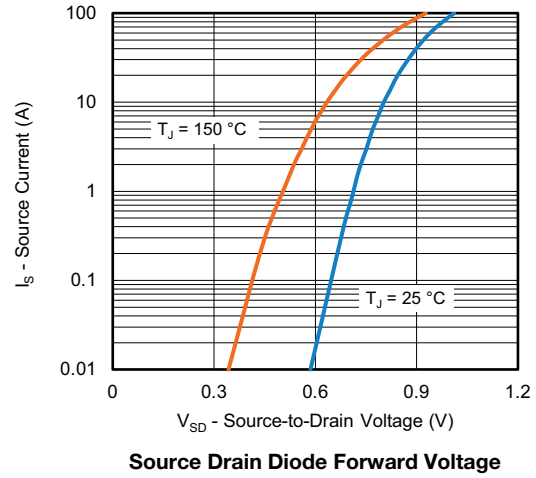
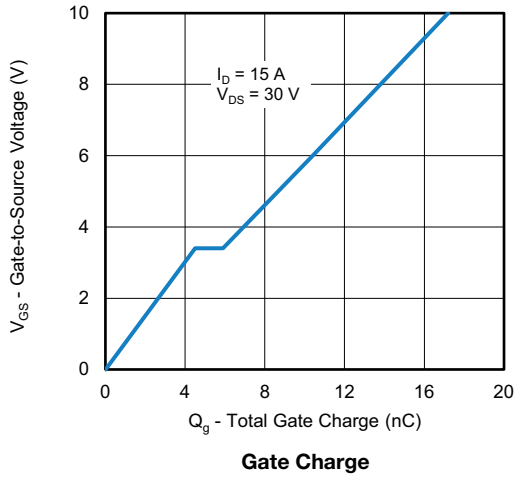
Transconductance



On-Resistance vs. Drain Current

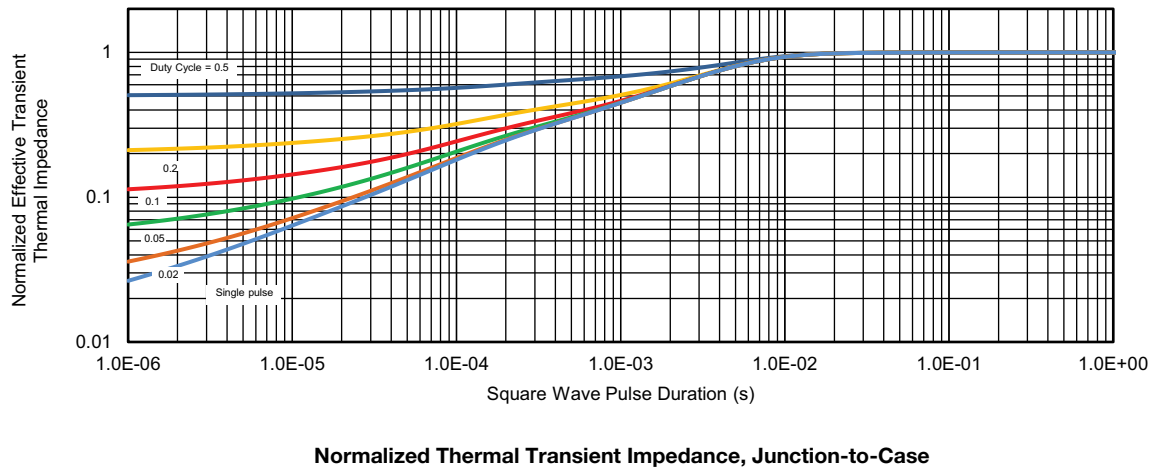
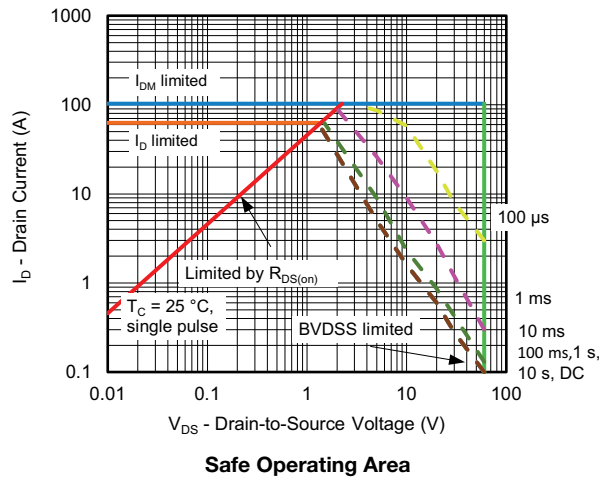


TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



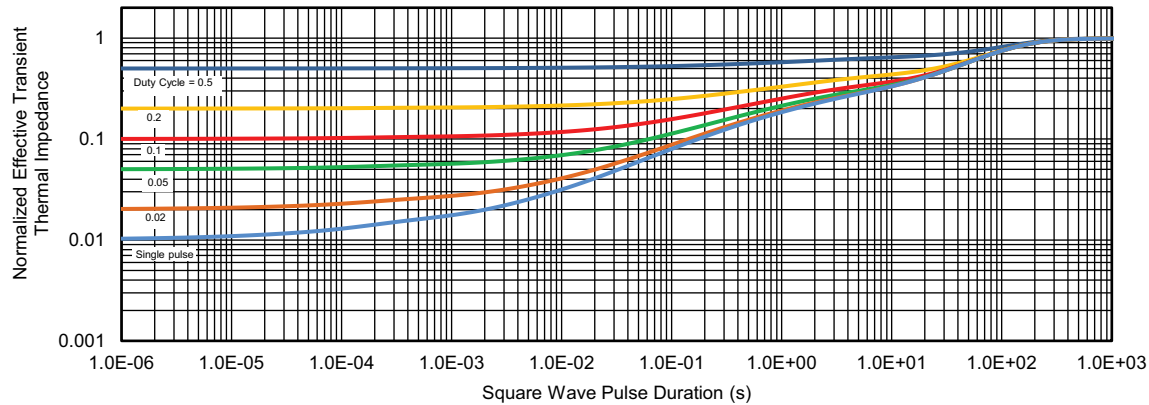


**THERMAL RATINGS** ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)





**THERMAL RATINGS** ( $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted)



**Normalized Thermal Transient Impedance, Junction-to-Ambient**

**Note**

- The characteristics shown in the two graphs
    - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
    - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)
- are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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